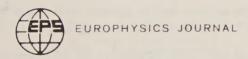
# Philosophical Magazine

First Published in 1798

Physics of Condensed Matter

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Published monthly Annual subscription 1986 £ 282 DM 1128 US \$620 ISSN 0141-8637 Dollar rates apply to USA, Canada and Mexico. Deutschmark rates to FR Germany. Sterling rates apply to the UK and all other areas

All subscriptions are payable in advance and all rates include postage. Journals are sent by air to the USA, Canada and Mexico, India and Australasia. Subscriptions are entered on an annual basis, i.e. from January to December. Payment may be made by sterling cheque, dollar cheque, international money order or National Giro, or by credit card (AMEX, VISA, Mastercard/Access).

Orders originating in the following territories should be sent direct to the local distributors

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 Japan
 Kinokuniya Company Ltd, Journal Department, PO Box 55 Chitose, Tokyo 156.

 New Zealand
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Taylor & Francis Inc., 242 Cherry Street, Philadelphia, Pennsylvania 19106–1906. Taylor & Francis Ltd, Rankine Road, Basingstoke, Hampshire RG24 0PR.

Air freight and mailing in the USA by Publications Expediting Inc., 200 Meacham Avenue, Elmont, New York 11003. Second class postage paid at Jamaica, New York 11431. US Postmaster: Send address changes to *Philosophical Magazine*, Publications Expediting Inc., 200 Meacham Avenue, Elmont, New York 11003.

Published by Taylor & Francis Ltd, 4 John Street, London WC1N 2ET, UK. Printed by Taylor & Francis (Printers) Ltd, Rankine Road, Basingstoke, Hampshire RG24 0PR, UK.

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